SiT9005 ADVANCED

1 to 141 MHz EMI Reduction Oscillator

Features

- Spread spectrum for EMI reduction
  - Wide spread % option
    - Center spread: from ±0.125% to ±2%, ±0.125% step
    - Down spread: -0.25% to -4% with -0.25% step
  - Spread profile option: Triangular, Hershey-kiss
- Programmable rise/fall time for EMI reduction: 8 options, 0.25 to 40 ns
- Any frequency between 1 MHz and 141 MHz accurate to 6 decimal places
- 100% pin-to-pin drop-in replacement to quartz-based XO's
- Excellent total frequency stability as low as ±20 ppm
- Operating temperature from -40°C to 85°C.
- Low power consumption of 4.0 mA typical at 1.8V
- Pin1 modes: Standby, output enable, or spread disable
- Fast startup time of 5 ms
- LVCMOS output
- Industry-standard packages
  - QFN: 2.0 x 1.6, 2.5 x 2.0, 3.2 x 2.5 mm^2
  - Contact SiTime for SOT23-5 (2.9 x 2.8 mm^2)
- RoHS and REACH compliant, Pb-free, Halogen-free and Antimony-free

Applications

- Printers
- Flat panel drivers
- PCIe
- Industrial motor
- High speed flat panel serial link

Electrical Specifications

Table 1. Electrical Characteristics

All Min and Max limits are specified over temperature and rated operating voltage with 15 pF output load unless otherwise stated. Typical values are at 25°C and 3.3V supply voltage.

Parameters	Symbol	Min.	Typ.	Max.	Unit	Condition
Frequency Range						
Output Frequency Range	f	1	–	141	MHz	
Frequency Stability and Aging						
Frequency Stability	F_stab	-20	–	+20	ppm	Inclusive of initial tolerance at 25°C, 1st year aging at 25°C, and variations over operating temperature, rated power supply voltage.
		-25	–	+25	ppm	
		-50	–	+50	ppm	
Operating Temperature Range						
Operating Temperature Range	T_use	-20	–	+70	°C	Extended Commercial
		-40	–	+85	°C	Industrial
Supply Voltage and Current Consumption						
Supply Voltage	Vdd	1.62	1.8	1.98	V	
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.7	3.0	3.3	V	
		2.97	3.3	3.63	V	
		2.25	–	3.63	V	
Current Consumption	Idd	–	5.6	6.5	mA	No load condition, f = 40 MHz, Vdd = 2.5V to 3.3V
		–	5.0	5.5	mA	No load condition, f = 40 MHz, Vdd = 1.8V
OE Disable Current	I_OD	–	5.0	6.5	mA	f = 40 MHz, Vdd = 2.5V to 3.3V, OE = GND, Output in high-Z state
		–	4.6	5.2	mA	f = 40 MHz, Vdd = 1.8V, OE = GND, Output in high-Z state
Standby Current	I_std	–	2.1	4.3	µA	$\overline{ST}$ = GND, Vdd = 2.5V to 3.3V, Output is weakly pulled down
		–	0.4	1.5	µA	$\overline{ST}$ = GND, Vdd = 1.8V, Output is weakly pulled down

Table 1. Electrical Characteristics (continued)

Parameters	Symbol	Min.	Typ.	Max.	Unit	Condition
LVCMOS Output Characteristics						
Duty Cycle	DC	45	–	55	%	
Rise/Fall Time	Tr, Tf	–	1	2	ns	Vdd = 2.5V, 2.8V, 3.0V or 3.3V, 20% - 80%, default derive strength
		–	1.3	2.5	ns	Vdd =1.8V, 20% - 80%, default derive strength
		–	–	2	ns	Vdd = 2.25V - 3.63V, 20% - 80%, default derive strength
Output High Voltage	VOH	90%	–	–	Vdd	IOH = -4 mA (Vdd = 3.0V or 3.3V) IOH = -3 mA (Vdd = 2.8V and Vdd = 2.5V) IOH = -2 mA (Vdd = 1.8V)
Output Low Voltage	VOL	–	–	10%	Vdd	IOL = 4 mA (Vdd = 3.0V or 3.3V) IOL = 3 mA (Vdd = 2.8V and Vdd = 2.5V) IOL = 2 mA (Vdd = 1.8V)
Input Characteristics						
Input High Voltage	VIH	70%	–	–	Vdd	Pin 1, OE or $\overline{ST}$
Input Low Voltage	VIL	–	–	30%	Vdd	Pin 1, OE or $\overline{ST}$
Input Pull-up Impedance[1]	Z_in	50	87	150	kΩ	Pin 1, OE logic high or logic low, or $\overline{ST}$ logic high
		2	–	–	MΩ	Pin 1, $\overline{ST}$ logic low
Startup and Resume Timing						
Startup Time	T_start	–	–	5	ms	Measured from the time Vdd reaches its rated minimum value
Enable/Disable Time	T_oe	–	–	180	ns	f = 40 MHz. For other frequencies, T_oe = 100 ns + 3 * cycles
Resume Time	T_resume	–	–	5	ms	Measured from the time ST pin crosses 50% threshold
Spread Enable Time	T_sde	–	–	4	µs	
Spread Disable Time	T_sdde	–	–	50	µs	
Jitter						
Cycle-to-cycle jitter	T_ccj	–	10.5	15	ps	f = 40 MHz, Vdd = 2.5 to 3.3V, Spread = ON(or OFF)
		–	8.5	12	ps	f = 40 MHz, Vdd = 3.3V, Spread = ON(or OFF)
		–	12.5	22	ps	f = 40 MHz, Vdd = 1.8V, Spread = ON(or OFF)

Notes:
1. At 30% and 70% VDD.

Table 2. Spread Spectrum %

Center Spread[2] (%)	Down Spread[2] (%)
±0.125	-0.25
±0.250	-0.50
±0.375	-0.75
±0.500	-1.00
±0.625	-1.25
±0.750	-1.50
±0.875	-1.75
±1.000	-2.00
±1.125	-2.25
±1.250	-2.50
±1.375	-2.75
±1.500	-3.00
±1.625	-3.25
±1.750	-3.50
±1.875	-3.50
±2.000	-4.00

Notes:
2. Contact SiTime for wider spread options

Table 3. Spread Profile

Spread Profile[3]
Triangular
Hershey-kiss

Notes:
3. Contact SiTime for random spread profile

Table 4. Pin Description

Pin	Symbol		Functionality
1	OE/ $\overline{ST}$ / NC/SD	Output Enable	H[4]: specified frequency output L: output is high impedance. Only output driver is disabled. Start up: output is high impedance. Only output driver is disabled.
		Standby	H[4]: specified frequency output L: output is low (week pull down). Device goes to sleep mode. Supply current reduced to I_std.
		No Connect	Pin1 has no function (Any voltage between 0 and Vdd or Open[4])
		Spread Disable	H: Spread = ON L: Spread = OFF
2	GND	Power	Electrical ground
3	OUT	Output	Oscillator output
4	VDD	Power	Power supply voltage[5]

Top View

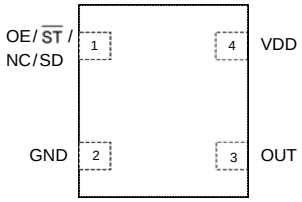


Figure 1. Pin Assignments

Notes:

4. In OE or $\overline{ST}$ mode, a pull-up resistor of 10 kΩ or less is recommended if pin 1 is not externally driven. If pin 1 needs to be left floating, use the NC option.
5. A capacitor of value 0.1 µF or higher between Vdd and GND is required.

Table 5. Absolute Maximum Limits

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
Vdd	-0.5	4	V
Electrostatic Discharge	–	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C
Junction Temperature[6]	–	150	°C

Note:

6. Exceeding this temperature for extended period of time may damage the device.

Rise/Fall Time (20% to 80%) vs C_{LOAD} Tables

Table 6. Vdd = 1.8V Rise/Fall Times for Specific C_{LOAD}

Rise/Fall Time Typ (ns)					
Drive Strength \ C_{LOAD}	5 pF	15 pF	30 pF	45 pF	60 pF
L	6.16	11.61	22.00	31.27	39.91
A	3.19	6.35	11.00	16.01	21.52
R	2.11	4.31	7.65	10.77	14.47
B	1.65	3.23	5.79	8.18	11.08
T	0.93	1.91	3.32	4.66	6.48
E	0.78	1.66	2.94	4.09	5.74
U	0.70	1.48	2.64	3.68	5.09
F or "-": default	0.65	1.30	2.40	3.35	4.56

Table 7. Vdd = 2.5V Rise/Fall Times for Specific C_{LOAD}

Rise/Fall Time Typ (ns)					
Drive Strength \ C_{LOAD}	5 pF	15 pF	30 pF	45 pF	60 pF
L	4.13	8.25	12.82	21.45	27.79
A	2.11	4.27	7.64	11.20	14.49
R	1.45	2.81	5.16	7.65	9.88
B	1.09	2.20	3.88	5.86	7.57
T	0.62	1.28	2.27	3.51	4.45
E or "-": default	0.54	1.00	2.01	3.10	4.01
U	0.43	0.96	1.81	2.79	3.65
F	0.34	0.88	1.64	2.54	3.32

Table 8. Vdd = 2.8V Rise/Fall Times for Specific C_{LOAD}

Rise/Fall Time Typ (ns)					
Drive Strength \ C_{LOAD}	5 pF	15 pF	30 pF	45 pF	60 pF
L	3.77	7.54	12.28	19.57	25.27
A	1.94	3.90	7.03	10.24	13.34
R	1.29	2.57	4.72	7.01	9.06
B	0.97	2.00	3.54	5.43	6.93
T	0.55	1.12	2.08	3.22	4.08
E or "-": default	0.44	1.00	1.83	2.82	3.67
U	0.34	0.88	1.64	2.52	3.30
F	0.29	0.81	1.48	2.29	2.99

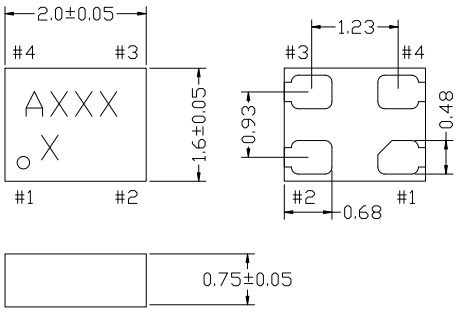
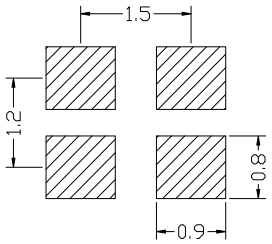
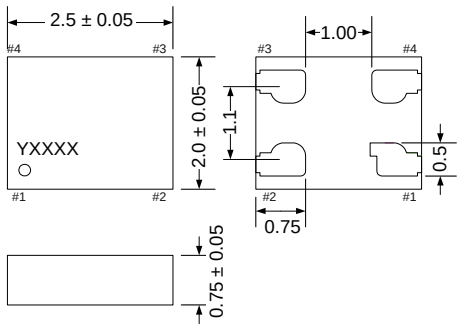
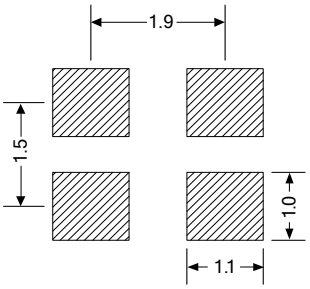
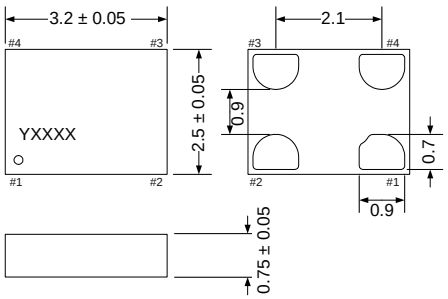
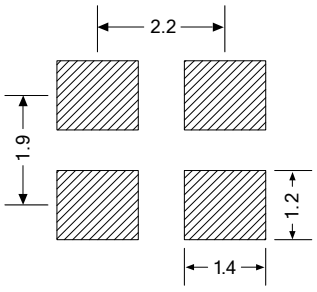
Table 9. Vdd = 3.0V Rise/Fall Times for Specific C_{LOAD}

Rise/Fall Time Typ (ns)					
Drive Strength \ C_{LOAD}	5 pF	15 pF	30 pF	45 pF	60 pF
L	3.60	7.21	11.97	18.74	24.30
A	1.84	3.71	6.72	9.86	12.68
R	1.22	2.46	4.54	6.76	8.62
B	0.89	1.92	3.39	5.20	6.64
T or "-": default	0.51	1.00	1.97	3.07	3.90
E	0.38	0.92	1.72	2.71	3.51
U	0.30	0.83	1.55	2.40	3.13
F	0.27	0.76	1.39	2.16	2.85

Table 10. Vdd = 3.3V Rise/Fall Times for Specific C_{LOAD}

Rise/Fall Time Typ (ns)					
Drive Strength \ C_{LOAD}	5 pF	15 pF	30 pF	45 pF	60 pF
L	3.39	6.88	11.63	17.56	23.59
A	1.74	3.50	6.38	8.98	12.19
R	1.16	2.33	4.29	6.04	8.34
B	0.81	1.82	3.22	4.52	6.33
T or "-": default	0.46	1.00	1.86	2.60	3.84
E	0.33	0.87	1.64	2.30	3.35
U	0.28	0.79	1.46	2.05	2.93
F	0.25	0.72	1.31	1.83	2.61

Dimensions and Patterns

Package Size – Dimensions (Unit: mm)[7]	Recommended Land Pattern (Unit: mm)[8]
2.0 x 1.6 x 0.75 mm 	
2.5 x 2.0 x 0.75 mm 	
3.2 x 2.5 x 0.75 mm 	

Notes:

7. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
8. A capacitor of value 0.1 µF or higher between Vdd and GND is required.

Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the SiTime Part Number Generator.

SiT9005AI-71-18EA25.000625D

Part Family
"SiT9005"

Revision Letter
"A" is the revision

Temperature Range
"C" Commercial -20ºC to 70ºC
"I" Industrial -40ºC to 85ºC

Output Drive Strength
"-" Default (datasheet limits)
See Tables 7 to 11 for rise/fall times

"L"	"T"
"A"	"E"
"R"	"U"
"B"	"F"

Package Size[9]
"7" 2.0 x 1.6 mm
"1" 2.5 x 2.0 mm
"2" 3.2 x 2.5 mm

Frequency Stability
"1" for ±20 ppm
"2" for ±25 ppm
"3" for ±50 ppm

Spread Type and Profile
"-" Center spread & Triangular (Default)
"H" Center spread & Hershey Kiss
"D" Down spread & Triangular
"G" Down spread & Hershey Kiss

Packing Method
"D": 8 mm Tape & Reel, 3ku reel
"E": 8 mm Tape & Reel, 1ku reel
Blank for Bulk

Frequency
1.000000 to 141.000000 MHz

Spread Percentage

		Center:	Down:
"A"	for	±0.125,	-0.25
"B"	for	±0.250,	-0.50
"C"	for	±0.375,	-0.75
"D"	for	±0.500,	-1.00
"E"	for	±0.625,	-1.25
"F"	for	±0.750,	-1.50
"G"	for	±0.875,	-1.75
"H"	for	±1.000,	-2.00
"I"	for	±1.125,	-2.25
"J"	for	±1.250,	-2.50
"K"	for	±1.375,	-2.75
"L"	for	±1.500,	-3.00
"M"	for	±1.625,	-3.25
"N"	for	±1.750,	-3.50
"O"	for	±1.875,	-3.75
"P"	for	±2.000,	-4.00

Feature Pin
"E" for Output Enable
"S" for Standby
"N" for No Connect
"D" for Spread Disablel

Supply Voltage
"18" for 1.8V ±10%
"25" for 2.5V ±10%
"28" for 2.8V ±10%
"30" for 3.0V ±10%
"33" for 3.3V ±10%
"XX" for 2.5V -10% to 3.3V +10%

Notes:
9. Contact SiTime for SOT23 (2.9 x 2.8 mm^2) package